



SANYO Semiconductors
DATA SHEET

LA74308LP

— **Monolithic Linear IC**
Audio Interface for DSC

Overview

The LA74308LP is a SPEAKER AMP and MIC AMP built-in audio interface for DSC. It incorporates an 8/16kHz trap and supports CODECs with a sampling rate of 8kHz or 16kHz.

Features

- Three-wire type SERIAL communication
- MIC AMP
- MIC power supply incorporated (with built-in pull-up resistor)
- ALC AMP
- 4th order LPF + trap (compatible with REC/PB changeover, trap frequency selectable from 8kHz and 16kHz)
- SPEAKER AMP (The BEEP signal can be mixed.)
- Electronic VOLUME (controlled by serial communication)
- LINE output (with SERIAL MUTE and MUTE transistor)
- STANDBY control

Specifications

Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		5.0	V
Allowable power dissipation	P _d max	T _a ≤85°C *	500	mW
Operating temperature	T _{opr}		-10 to +85	°C
Storage temperature	T _{stg}		-55 to +150	°C

* Printed circuit board mounting condition (40mm × 50mm × 0.8mm: glass epoxy) 2S2P (Four layers printed circuit board)

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Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended operating voltage	V _{CCA}		3.0	V
	V _{CCSP}		3.3	V
Allowable operating voltage range	V _{CCAO}		2.7 to 3.6	V
	V _{CCSPO}	Take care not to exceed Pd max.	2.7 to 3.6	V

Electrical Characteristics at Ta=25°C, V_{CCA}=3.0V, V_{CCSP}=3.3V, f=1kHz, with the VREF capacitance charging circuit in the OFF MODE

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Circuit current						
V _{CCA} current dissipation at no signal 1	I _{CCA1}	V _{CCA} =3.0V:REC BLOCK(MIC/ALC/REC AMP) POWER SAVE MODE	4.9	6.6	8.3	mA
V _{CCA} current dissipation at no signal 2	I _{CCA2}	V _{CCA} =3.0V, LINE/SP AMP POWER SAVE MODE	6.2	8.3	10.4	mA
V _{CCA} standby current dissipation 1	I _{CCAS1}	V _{CCA} =3.0V, during standby control V3=0V			1	µA
V _{CCA} standby current dissipation 2	I _{CCAS2}	V _{CCA} =3.0V, BIAS MODE			800	µA
V _{CCSP} current dissipation at no signal 1	I _{CCS1}	V _{CCSP} =3.3V, SPK POWER ON MODE	1	2	4	mA
V _{CCSP} current dissipation at no signal 2	I _{CCS2}	V _{CCSP} =3.3V, SPK POWER SAVE MODE		0.05	0.1	mA
V _{CCSP} standby current dissipation 1	I _{CCSS1}	V _{CCSP} =3.3V, during standby control (0V applied to pin 3)			9	µA
V _{CCSP} standby current dissipation 2	I _{CCSS2}	V _{CCSP} =3.3V, BIAS MODE			9	µA
REC output system						
REC reference output LEVEL	VOR	ALC IN, V _{IN} =-53dBV	-11	-9.5	-8	dBV
REC reference output distortion	HDR1	ALC IN, V _{IN} =-53dBV, THD: from 2nd to 5th harmonic		0.1	0.2	%
ALC characteristics	ALM	ALC IN, V _{IN} =-20dBV	-3	-1.8		dBV
ALC distortion	ALMD	ALC IN, V _{IN} =-20dBV, THD: from 2nd to 5th harmonic		0.3	1	%
ALC IN max input level	VINRMX	ALC IN LEVEL at which REC output THD (from 2nd to 5th harmonic) becomes 3% or less.			-7	dBV
REC output noise voltage	VNOR	ALC IN, no input, JIS-A Filter		-70	-60	dBV
LINE output system (LINE load = as measured at the 22kΩ end)						
LINE reference output LEVEL	VOL	PB IN, V _{IN} =-17dBV	-11	-9.5	-8	dBV
LINE reference output distortion	HDL	PB IN, V _{IN} =-17dBV, THD: from 2nd to 5th harmonic		0.1	0.2	%
LINE reference output noise voltage	VNOL	PB IN, no input, JIS-A Filter		-77	-69	dBV
PB IN max input LEVEL	VINPMX	PB IN LEVEL at which LINE output THD (from 2nd to 5th harmonic) becomes 1% or less.			-9	dBV
LINE output frequency characteristics 1	FEQP1	PB IN, V _{IN} =-10dBV, comparison of f=3kHz/1kHz	-3.5	-2		dB
LINE output frequency characteristics 2	FEQP2	PB IN, V _{IN} =-10dBV, comparison of f=4kHz/1kHz		-10	-6	dB
LINE output frequency characteristics 3	FEQP3	PB IN, V _{IN} =-10dBV, comparison of f=8kHz/1kHz		-55	-30	dB
SP output system (SP load = as measured at the 8Ω end)						
SP reference output LEVEL1 (Vol.MAX)	VOSP1	PB IN, V _{IN} =-17dBV, Vol=MAX (EVR DATA=31)	-6	-3	0	dBV
SP reference output distortion	THDSP	PB IN, V _{IN} =-17dBV, Vol=MAX, THD: from 2nd to 5th harmonic		0.4	1	%
SP reference output LEVEL2 (Vol.TYP)	VOSP2	PB IN, V _{IN} =-17dBV, Vol=TYP (EVR DATA=14)	-18	-12	-6	dBV
SP reference output LEVEL3 (Vol.MIN)	VOSP3	PB IN, V _{IN} =-17dBV, Vol=MIN (EVR DATA=0) JIS-A Filter		-80	-70	dBV
SP reference output noise voltage	VNOSP	PB IN no input, Vol=MAX, JIS-A Filter		-70	-64	dBV
SP maximum ratings output	VOMSP	PB IN, Vol=MAX, LEVEL at which THD=10%	200	320		mW

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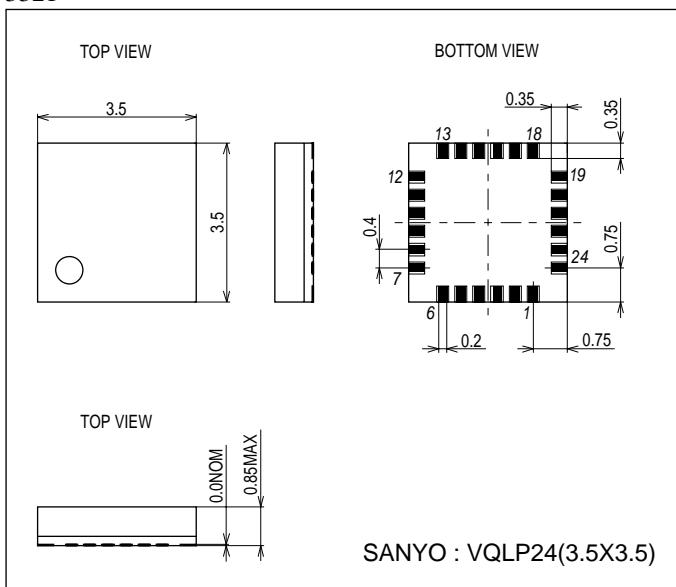
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
MIC output system						
MIC voltage gain	VGMIC	MIC IN, $V_{IN}=-36\text{dBV}$	16	17	18	dB
MIC output distortion	HDMIC	MIC IN, $V_{IN}=-36\text{dBV}$, THD: from 2nd to 5th harmonic		0.05	0.1	%
MIC output noise voltage	VNOMIC	MIC IN, no input, JIS-A Filter		-94	-83	dBV
MIC IN max input level	VINMMX	MIC IN LEVEL at which the MIC output THD (from 2nd to 5th harmonic) becomes 3% or less.			-25	dBV
MIC V_{CC} output voltage	VMIC	At $6.2\text{k}\Omega$ load	1.5	1.7	1.9	V
Control system						
Serial CLOCK frequency	FCLK			0.1	1	MHz
Serial input LOW level	SERLO		0		0.7	V
Serial input HIGH level	SERHI		2.3		3.5	V

Package Dimensions

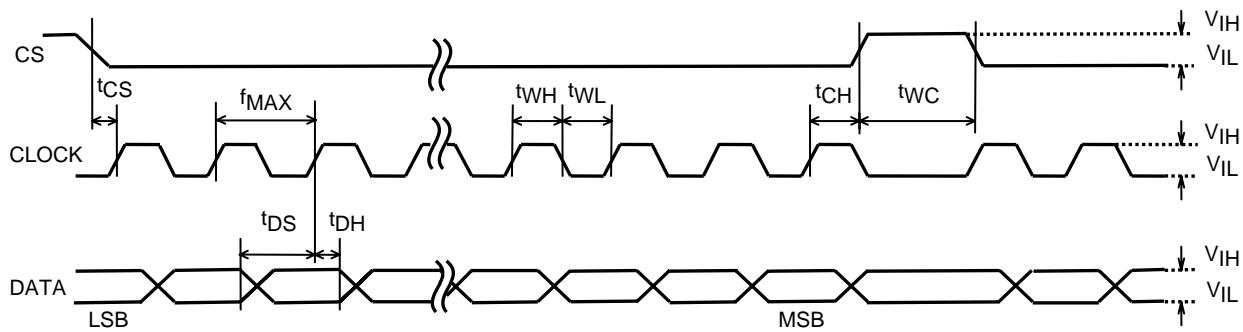
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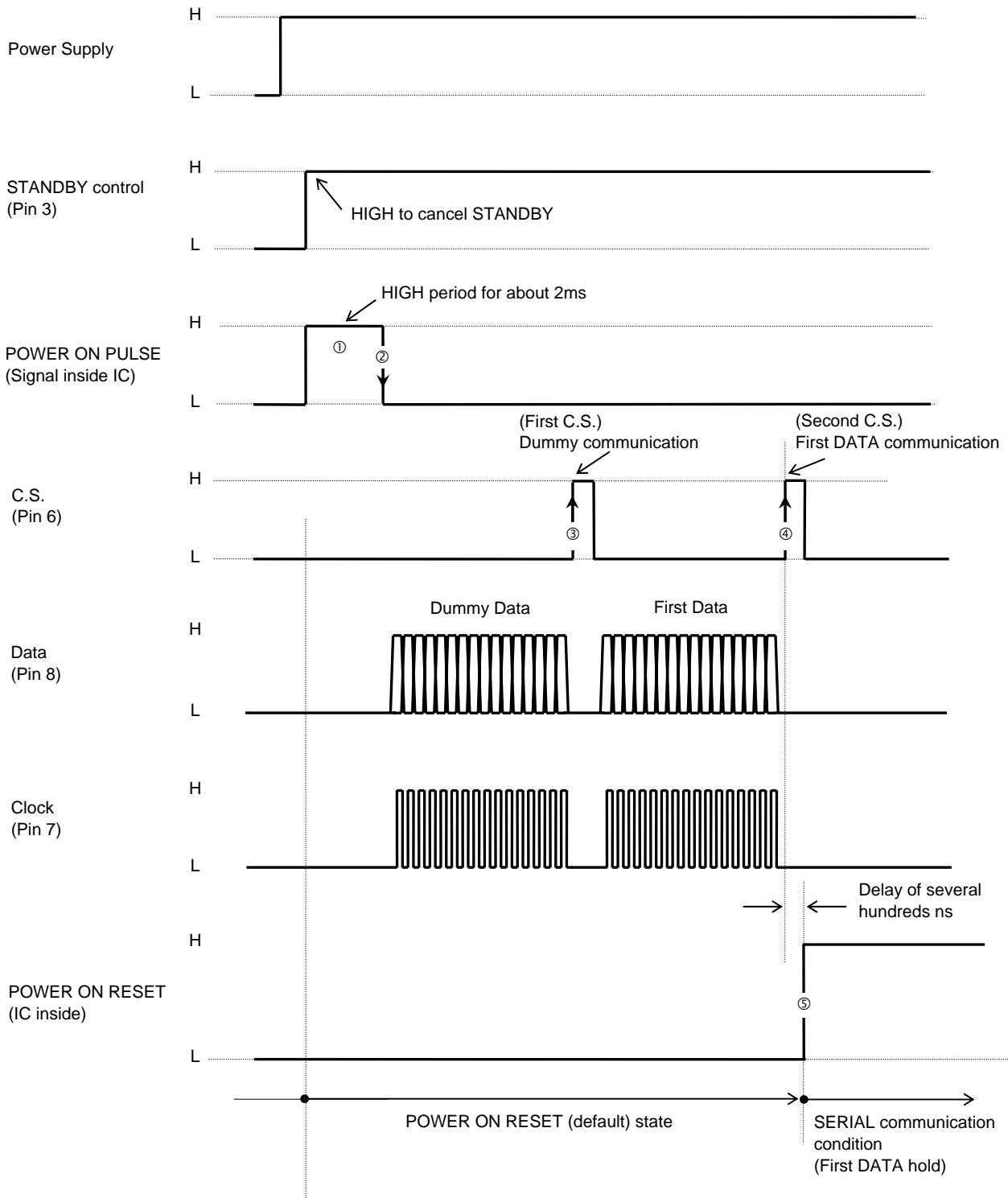
Description of the Content of Serial Communication

DATA No.	Parameter	Default
0	LINE MUTE Tr. 0:OFF, 1:ON	1
1	VREF capacitance charging circuit SW 0:OFF, 1:ON	1
2	MIC AMP POWER SW 0:ON, 1:OFF	1
3	ALC AMP POWER SW 0:ON, 1:OFF	1
4	REC/PB changeover SW 0:PB, 1:REC	0
5	LPF characteristics (TRAP) changeover SW 0:16kHz, 1:8kHz	1
6	REC AMP POWER SW 0:ON, 1:OFF	1
7	LINE OUT POWER SW 0:ON, 1:OFF	1
8	LINE MUTE SW 0:OFF, 1:ON	1
9	SPK POWER SW 0:ON, 1:OFF	1
10	DATA=1 1 1 1 1 1:VOL MAX	0
11	DATA=2 l	0
12	DATA=4 0 0 0 0 0:VOL MIN (MUTE)	0
13	DATA=8 * EVR setting (the numeral shown in the left is decimal.)	0
14	DATA=16 For characteristics, see P12.)	0
MSB	15 BIAS MODE 0:ACTIVE MODE, 1:BIAS MODE	0

Serial Transmission Timing

- fMAX (Max clock frequency) 1.0MHz
- tWL (Clock pulse width: Low) 500ns or more
- tWH (Clock pulse width: High) 500ns or more
- tCS (Chip enable setup time) 500ns or more
- tCH (Chip enable hold time) 500ns or more
- tDS (Data setup time) 500ns or more
- tDH (Data hold time) 500ns or more
- tWC (Chip enable pulse width) 500ns or more
- VIL (High voltage lower limit) 2.3V to 3.5V
- VIH (Low voltage upper limit) 0.0V to 0.7V

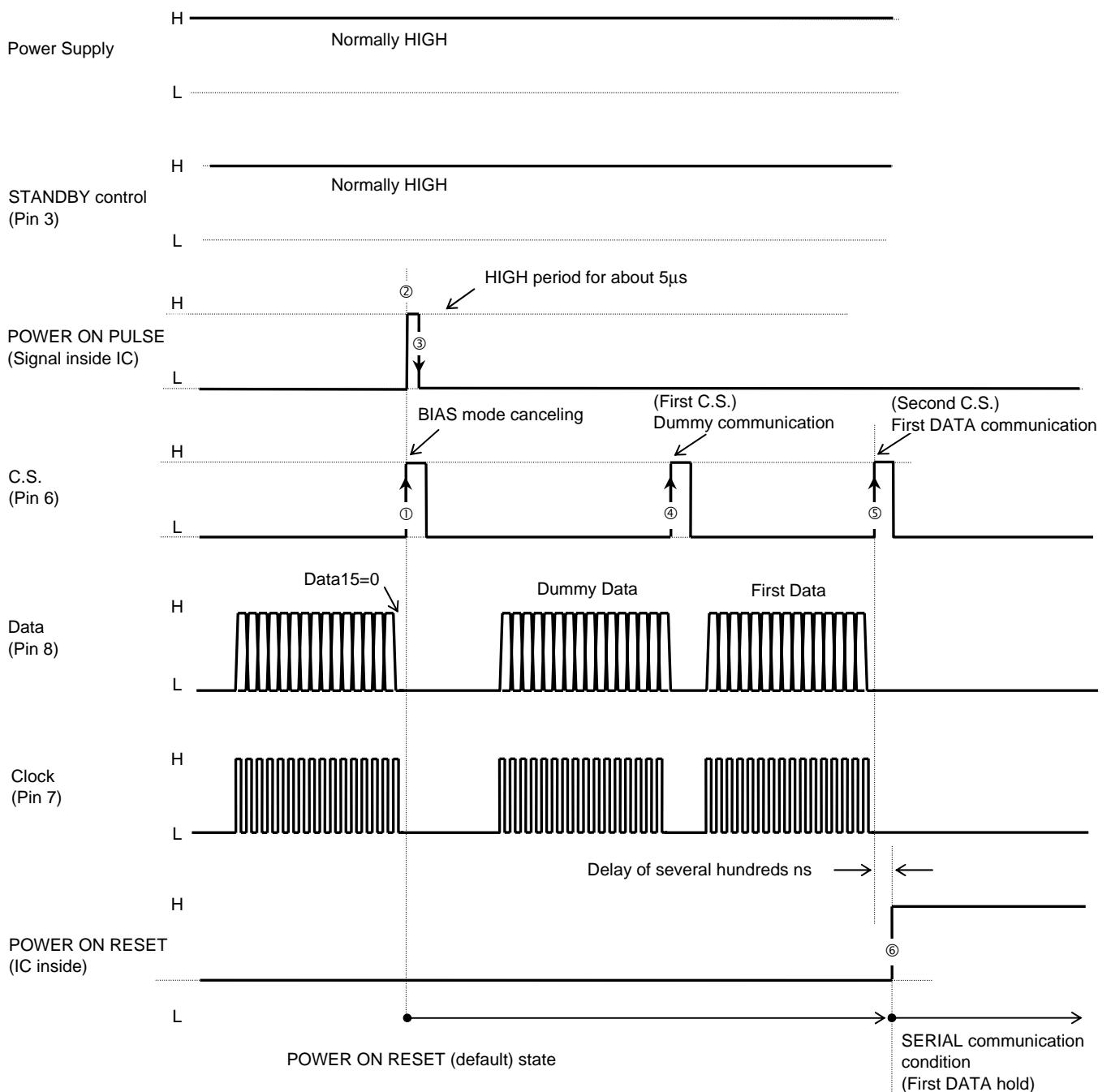
POWER ON RESET Condition (SERIAL communication)



The POWER ON RESET state covers a period up to the rise ④ of the second C.S. input after fall ② of POWER ON PULSE ① generated inside IC when the power is supplied and the STANDBY control is canceled. ③ is the dummy communication.

Actually, because of delay of several hundreds ns in the IC, the first DATA condition begins in ⑤ and the normal SERIAL communication condition begins after ⑤.

BIAS MODE Canceling State (SERIAL communication)



The POWER ON RESET state from the BIAS MODE covers the period from the rise of C.S. ① for communication of canceling of the BIAS MODE to the second rise ⑤ of CS input after the fall ③ of POWER ON PULSE ② generated inside IC. ④ is the dummy communication.

Actually, because of delay of several hundreds ns in the IC, the first DATA condition begins in ⑥ and the normal SERIAL communication condition begins after ⑥.

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Electrical Characteristics Measurement Method at Ta=25°C, VCCA=3.0V, VCCSP=3.3V, f=1kHz with the VREF capacitance charging circuit in the OFF MODE

No.	Symbol	Pin	Input	Output	STANDBY pin	Serial control setting											
						0	1	2	3	4	5	6	7	8	9	10	
Circuit current																	
1	ICCA1	T11	VCCA=3.0V No input	T11	VREF capacitance charging circuit in the OFF MODE MIC/ALC/REC AMP POWER SAVE MODE	3.3V	0	0	1	1	0	1	1	0	0	0	0
2	ICCA2	T11	VCCA=3.0V No input	T11	VREF capacitance charging circuit in the OFF MODE LINE/SP AMP POWER SAVE MODE	3.3V	0	0	0	0	1	1	0	1	0	0	0
3	ICCAS1	T11	VCCA=3.0V No input	T11	With the STANDBY pin V3=0V	0V	0	0	0	0	0	1	0	0	0	0	0
4	ICCAS2	T11	VCCA=3.0V No input	T11	BIAS MODE	3.3V	0	0	0	0	0	1	0	0	0	0	1
5	ICCS1	T22	VCCSP=3.3V No input	T22	VREF capacitance charging circuit in the OFF MODE SPK POWER ON MODE	3.3V	0	0	1	1	0	1	0	0	0	0	0
6	ICCS2	T22	VCCSP=3.3V No input	T22	VREF capacitance charging circuit in the OFF MODE SPK POWER SAVE MODE	3.3V	0	0	1	1	0	1	1	0	0	0	0
7	ICCSS1	T22	VCCSP=3.3V No input	T22	With the STANDBY pin V3=0V	0V	0	0	1	1	0	1	0	0	0	0	0
8	ICCSS2	T22	VCCSP=3.3V No input	T22	Bias MODE	3.3V	0	0	1	1	0	1	0	0	0	0	1
REC output system																	
9	VOR	T14	V _N =53dBV f=1kHz	T12	400 to 20kHz LPF used SW14=A, SW16=B	3.3V	0	0	0	0	1	1	0	1	1	0	0
10	HDR1	T14	V _N =53dBV f=1kHz	T12	400 to 20kHz LPF used SW14=A SW16=B, THD: from 2nd to 5th harmonic	3.3V	0	0	0	0	1	1	0	0	0	0	0
11	ALM	T14	V _N =20dBV f=1kHz	T12	400 to 20kHz LPF used, SW14=A, SW16=B	3.3V	0	0	0	0	1	1	0	1	1	0	0
12	ALMD	T14	V _N =20dBV f=1kHz	T12	400 to 20kHz LPF used, SW14=A SW16=B, THD: from 2nd to 5th harmonic	3.3V	0	0	0	0	1	1	0	1	1	0	0
13	VINRNM	T14	f=1kHz	T12	400 to 20kHz LPF used, SW16=B Pin 14 level at which pin 12 becomes THD = 3% from 2nd to 5th harmonic	3.3V	0	0	0	1	1	0	1	1	0	0	0
14	VNOR	T14	No input	T12	JIS-A FILTER used SW14=B, SW16=B	3.3V	0	0	0	0	1	1	0	1	1	0	0

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No.	Symbol	Pin	Input Conditions	Output	STANDBY pin	Serial control setting													
						0	1	2	3	4	5	6	7	8	9	10	11	12	
15	VOL1	T10	$V_{IN}=-17dBV$ $f=1kHz$	T5	400 to 20kHz LPF used SW10=A, SW16=A	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
16	HDL	T10	$V_{IN}=-17dBV$ $f=1kHz$	T5	400 to 20kHz LPF used, THD: from 2nd to 5th harmonic SW16=A, THD: from 2nd to 5th harmonic	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
17	VNOL	T10	No input	T5	JIS-A FILTER used, SW10=B, SW16=A	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
18	VINPMX	T10	$f=1kHz$	T5	400 to 20kHz LPF used, SW10=A, Pin 10 level at which pin 5 becomes THD = 3% (from 2nd to 5th harmonic)	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
19	FEQP1	T10	$V_{IN}=-10dBV$ $f=3kHz$	T5	$f=3kHz/1kHz$ level ratio SW10=A, SW16=A	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
20	FEQP2	T10	$V_{IN}=-10dBV$ $f=4kHz$	T5	$f=4kHz/1kHz$ level ratio SW10=A, SW16=A	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
21	FEQP3	T10	$V_{IN}=-10dBV$ $f=8kHz$	T5	$f=8kHz/1kHz$ level ratio SW10=A, SW16=A	3.3V	0	0	1	1	0	1	1	0	0	1	0	0	
SPK output system (SPK end: measured with 3Ω)																			
22	VOSP1	T10	$V_{IN}=-17dBV$ $f=1kHz$	T21	400 to 20kHz LPF used Vol.=MAX (EVR DATA=31)	3.3V	0	0	1	1	0	1	1	1	0	1	1	1	0
23	THDSP	T10	$V_{IN}=-17dBV$ $f=1kHz$	T21	400 to 20kHz LPF used, Vol.=MAX THD: from 2nd to 5th harmonic	3.3V	0	0	1	1	0	1	1	1	0	1	1	1	0
24	VOSP2	T10	$V_{IN}=-17dBV$ $f=1kHz$	T21	400 to 20kHz LPF used Vol.=TYP (EVR DATA=14)	3.3V	0	0	1	1	0	1	1	1	0	0	1	1	0
25	VOSP3	T10	$V_{IN}=-17dBV$ $f=1kHz$	T21	JIS-A FILTER used Vol.=MIN (EVR DATA=0)	3.3V	0	0	1	1	0	1	1	1	0	0	0	0	0
26	VNOSP	T10	No input	T21	JIS-A FILTER used Vol.=MAX (EVR DATA=31)	3.3V	0	0	1	1	0	1	1	1	0	1	1	1	0
27	VOSSP	T10	$f=1kHz$	T21	400 to 20kHz LPF used Vol.=MAX (EVR DATA=31) Level at which Vol.=MAX and THD=10% (from 2nd to 5th harmonic)	3.3V	0	0	1	1	0	1	1	1	0	1	1	1	0

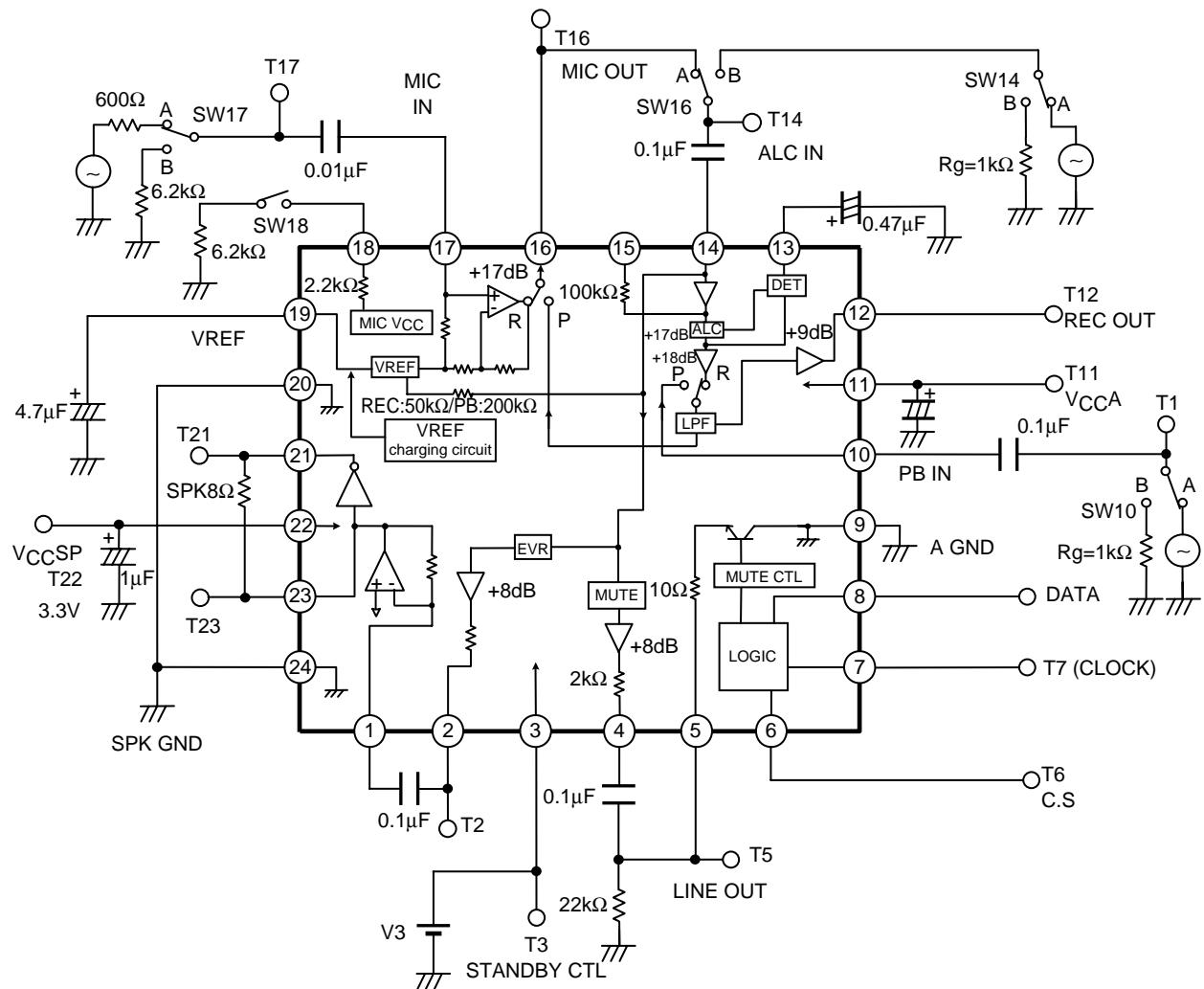
No.	Symbol	Pin	Input Conditions	Output	STANDBY pin	Serial control setting														
						0	1	2	3	4	5	6	7	8	9	10	11	12	13	14
						LINE Mute Tr.	VREF charging SW	MIC P SW	ALC P SW	REC /PB SW	LPF TRAP	LINE P SW	SPK P SW	LINE Mute	EV R1 DATA	EV R2 DATA	EV R4 DATA	EV R8 DATA	EV R16 DATA	Bias MODE
MIC Output system																				
28	VGMIC	T17	$V_{IN}=-36\text{dBV}$ $f=1\text{kHz}$	T16	400 to 20kHz LPF used, SW17=A	3.3V	0	0	0	0	1	1	0	1	1	1	0	0	0	0
29	HDMIC	T17	$V_{IN}=-36\text{dBV}$ $f=1\text{kHz}$	T16	400 to 20kHz LPF used, SW17=A THD: from 2nd to 5th harmonic	3.3V	0	0	0	0	1	1	0	1	1	0	0	0	0	0
30	VNOMIC	T17	No input	T16	JIS-A FILTER used, SW17=B	3.3V	0	0	0	0	1	1	0	1	1	0	0	0	0	0
31	VINMMX	T17	$f=1\text{kHz}$	T16	400 to 20kHz LPF used, SW17=A Pin 17 level at which pin 16 becomes THD = 3% (from 2nd to 5th harmonic)	3.3V	0	0	0	0	1	1	0	1	1	0	0	0	0	0
32	VMIC	T17	No input	T18	Pin 18 Measurement of output voltage (under $6.2\text{k}\Omega$ load) SW18=ON	3.3V	0	0	0	0	1	1	0	1	1	0	0	0	0	0

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Description of Pin Functions

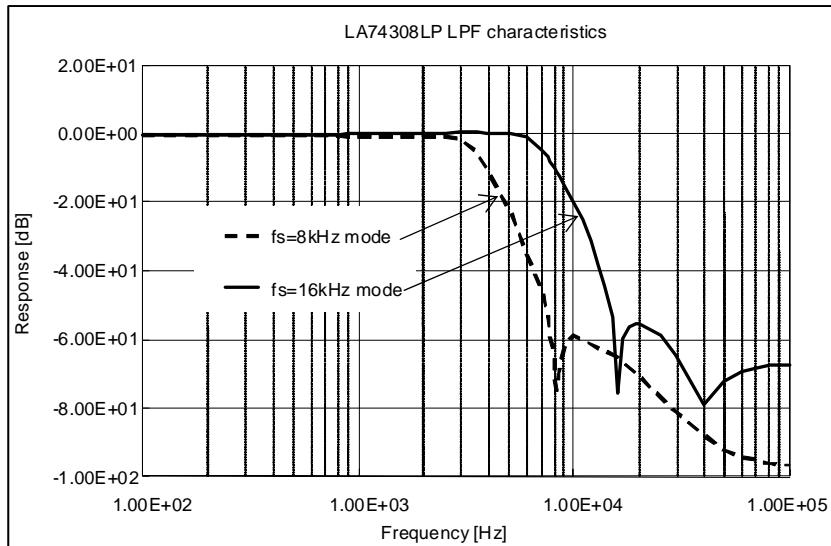
Pin No.	Pin Description
1	Speaker input
2	EVR output
3	STANDBY control
4	LINE output
5	LINE MUTE Tr. output
6	C.S. input
7	CLOCK input
8	DATA input
9	GND
10	PB input
11	V _{CCA}
12	REC output
13	ALC detection
14	ALC input
15	2nd order HPF
16	MIC output
17	MIC input
18	INT power supply for MIC
19	Ripple rejection for VREFL
20	SPK GND
21	Speaker positive-phase output
22	V _{CCSP}
23	Speaker negative-phase output
24	SPK GND

Block Diagram

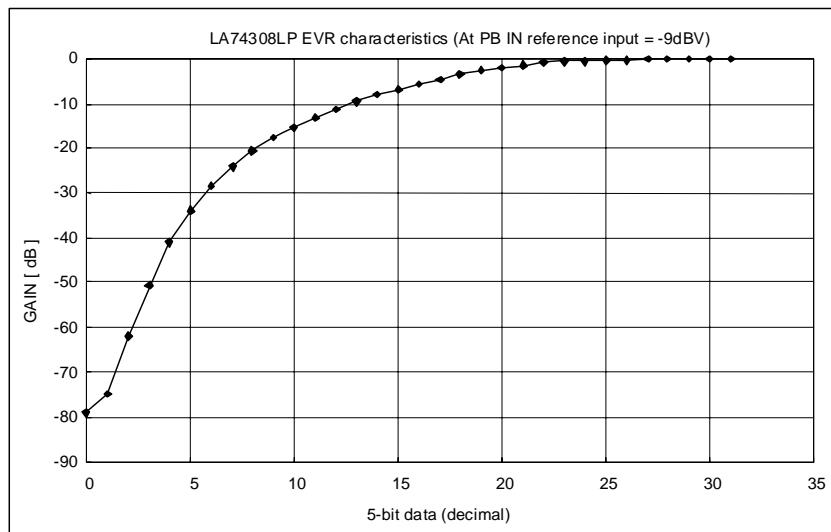


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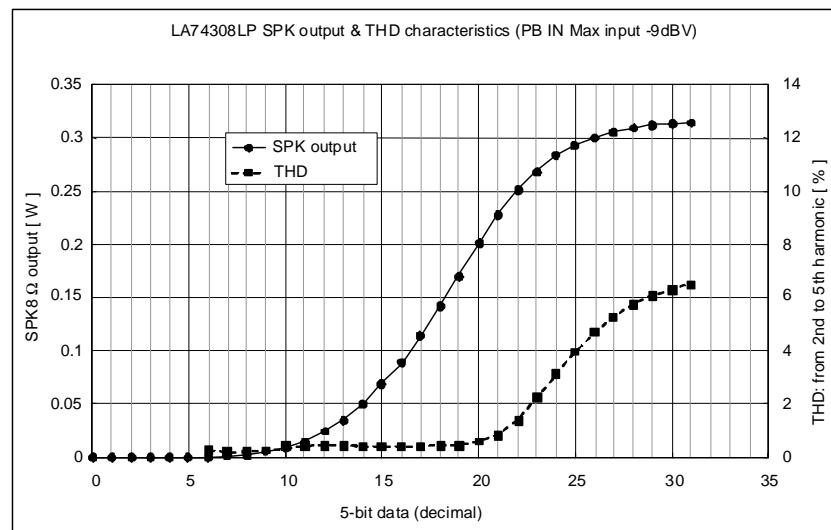
LPF Characteristics



EVR Characteristics

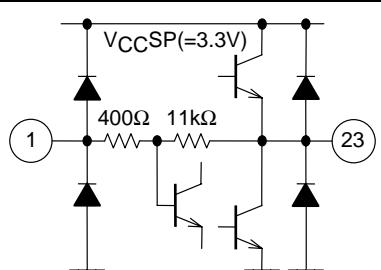
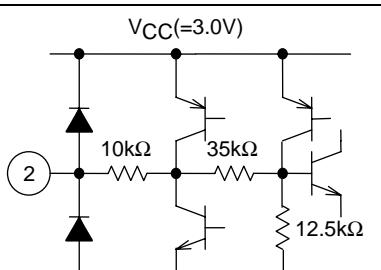
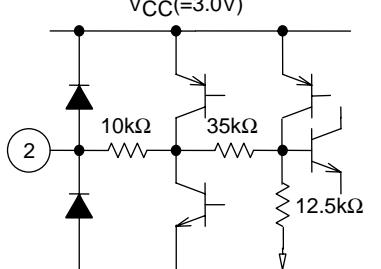
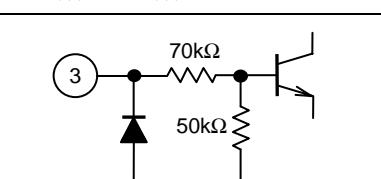
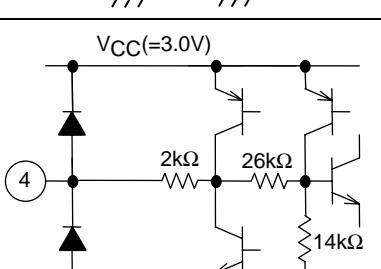
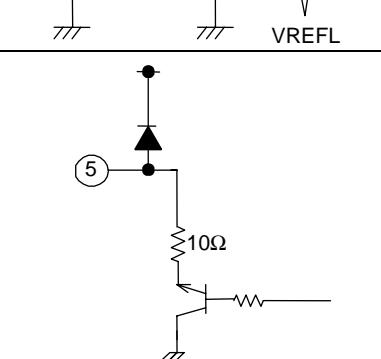
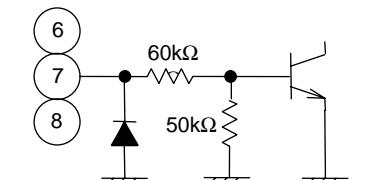
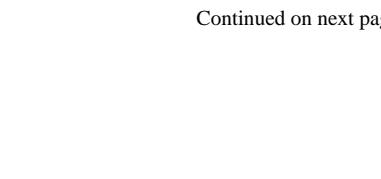


SPK Output Level & Distortion Rate



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LA74308LP Input/output Pattern Table

PIN	Pin Name	DC voltage	AC voltage	Description of functions	Equivalent circuit diagram in pin
1	SP IN	1.27V	At PB reference input Output level = -9dBV (EVR MAX)	Speaker input pin	
23	SPK OUT-	1.27V	At PB reference input Output level = -9dBV (EVR MAX)	Speaker negative-phase output pin	
2	EVR OUT	1.5V		EVR output pin	
3	STANDBY L			STANDBY control pin 2V or more: STANDBY canceled	
4	LINE OUT			LINE output pin	
5	LINE MUTE	1.5V	At PB reference input Output level = -9dBV	LINE output mute transistor	
6	CS			CS input pin	
7	CLOCK			CLOCK input pin	
8	DATA			DATA input pin	

Continued on next page.

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PIN	Pin Name	DC voltage	AC voltage	Description of functions	Equivalent circuit diagram in pin
9	GND	0V		GND pin	
10	PB IN	1.5V	Reference input level =-17dBV	PB input pin	
11	V _{CC}	3V		Power supply pin	
12	REC OUT	1.5V	Reference input level =-9dBV	R output pin	
13	ALC DET			ALC detection pin	
14	ALC IN (REC)	1.5V	Reference input level =-53dBV Max input level =-8dBV	ALC input pin	
	EVR IN (PB)	1.5V		EVR input pin	
15	HPF	1.5V		Used when forming the 2nd order HPF	

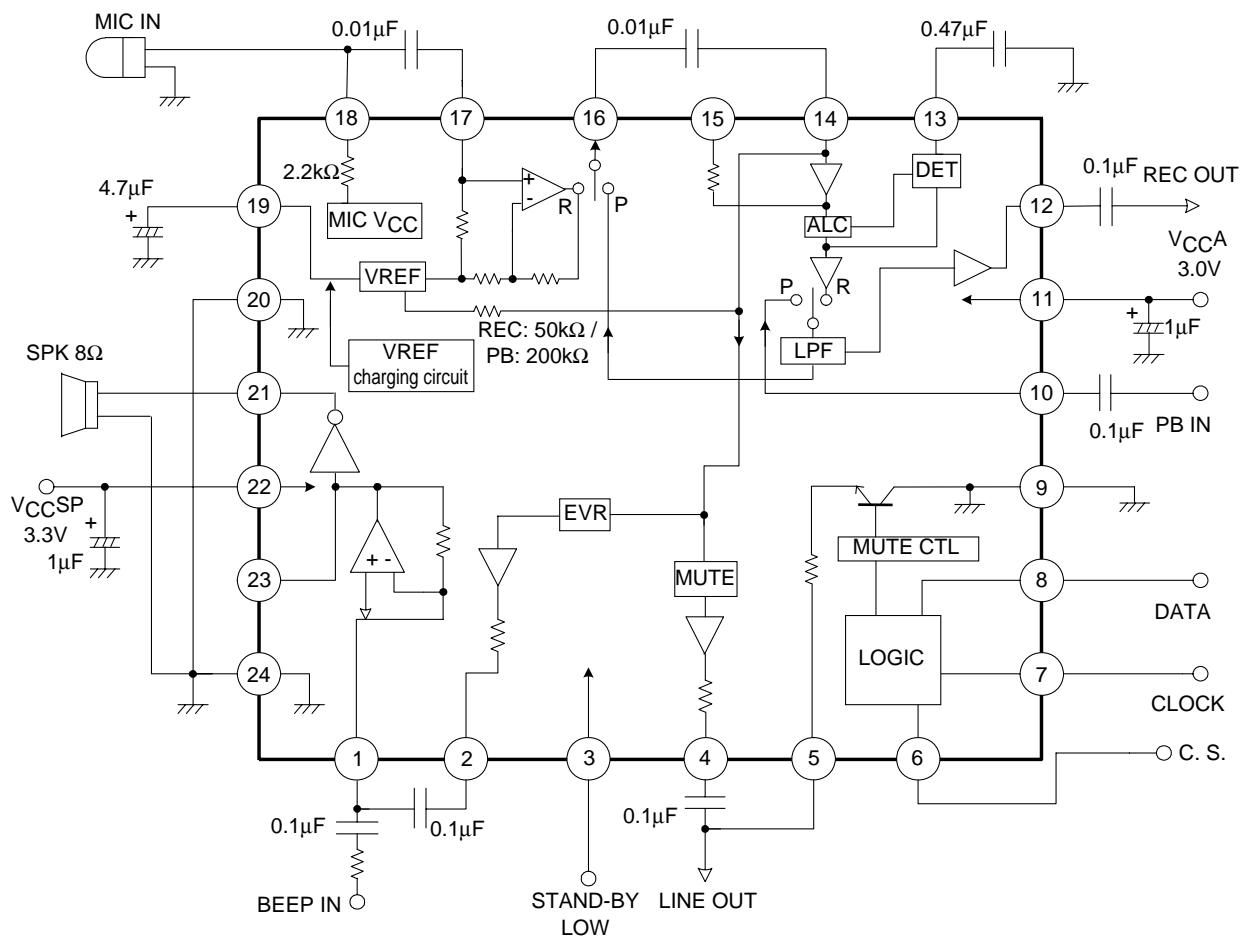
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LA74308LP

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PIN	Pin Name	DC voltage	AC voltage	Description of functions	Equivalent circuit diagram in pin
16	MIC OUT (REC)	1.5V		MIC output pin (for REC mode)	
	LPF OUT (PB)			LPF output pin (for PB mode)	
17	MIC IN	1.5V	Reference input level =-70dBV Max input level =-25dBV	MIC input pin	
18	MIC V _{CC}	2.30V		MIC power pin	
19	VREFL	2.30V		MIC V _{CC} and VREFL ripple rejection pin	
20 24	SP GND	0V		Speaker GND pin	
21	SPK OUT+	1.27V	At PB reference input Output level = -9dBV (EVR MAX)	Speaker positive-phase output pin	
22	V _{CCSP}	3.3V		Speaker power pin	

Application Circuit



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